L Number	Hits	Search Text	DB	Time stamp
76	60	(((laser NEAR diode) with (ridge or stripe)) and	USPAT;	2003/04/03 14:04
		clad\$4 and active and contact and electrode and	US-PGPUB;	
		voltage) and 372/46	EPO; JPO;	
			DERWENT;	
			IBM TDB	
87	111	((laser NEAR diode) with (ridge or stripe)) and	USPAT;	2003/04/03 14:06
		(clad\$4 near (layer or region or medium or film)) and	US-PGPUB;	
		(active near (layer or region or medium or film)) and	EPO; JPO;	
		(contact near (layer or region or medium or film)) and	DERWENT;	
ĺ		electrode and 372/46	IBM TDB	
94	52	(((laser NEAR diode) with (ridge or stripe)) and	USPAT;	2003/04/03 14:10
	02	(clad\$4 near (layer or region or medium or film)) and	US-PGPUB;	
		(active near (layer or region or medium or film)) and	EPO; JPO;	
1		(contact near (layer or region or medium or film)) and	DERWENT;	
		electrode and 372/46) and voltage	IBM TDB	
101	10		USPAT;	2003/04/03 14:10
101	10	1 ,,,		2003/04/03 14.10
		(clad\$4 near (layer or region or medium or film)) and	US-PGPUB;	
		(active near (layer or region or medium or film)) and	EPO; JPO;	
		(contact near (layer or region or medium or film)) and	DERWENT;	
	_	electrode and 372/46) and third near clad\$4	IBM_TDB	000010410040
108	0	clad\$ and laesr near diode and (etch\$4 near stop)	USPAT;	2003/04/03 16:06
			US-PGPUB;	
			EPO; JPO;	
		•	DERWENT;	
			IBM_TDB	
115.	320	clad\$ and (laser near diode) and (etch\$4 near stop)	USPAT;	2003/04/03 16:07
			US-PGPUB;	
	•		EPO; JPO;	
İ			DERWENT;	
			IBM_TDB	
122	258	clad\$ and (laser near diode) and (etch\$4 near stop	USPAT;	2003/04/03 16:08
		near layer)	US-PGPUB;	
		•	EPO; JPO;	
		·	DERWENT;	
			IBM TDB	
129	5	laser and clad\$4 and active and contact and	USPAT;	2003/04/03 16:08
	•	electrode and (injection near2 stripe) and (etching	US-PGPUB;	
Ì		near stop near (layer or region or medium or film))	EPO; JPO;	
		Thou stop hour hayer or region or modium or many	DERWENT;	
			IBM TDB	
136	166	laser and clad\$4 and active and contact and	USPAT;	2003/04/03 16:40
130	100	electrode and (ridge or stripe) and (etching near stop	US-PGPUB;	2003/04/03 10:40
			EPO; JPO;	•
İ		near (layer or region or medium or film))	DERWENT;	
1.10	00	Hanna and shadou and and and an area and a	IBM_TDB	2002/04/02 46-22
143	98	(laser and clad\$4 and active and contact and	USPAT;	2003/04/03 16:33
		electrode and (ridge or stripe) and (etching near stop	US-PGPUB;	
		near (layer or region or medium or film))) and 372/46	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
150	1	((laser and clad\$4 and active and contact and	USPAT;	2003/04/03 16:35
		electrode and (ridge or stripe) and (etching near stop	US-PGPUB;	
		near (layer or region or medium or film))) and	EPO; JPO;	
		372/46) and saturatable near absorption	DERWENT;	
	i		IBM TDB	

				0000104100 40 05
157	8	((laser and clad\$4 and active and contact and	USPAT;	2003/04/03 16:35
		electrode and (ridge or stripe) and (etching near stop	US-PGPUB;	
		near (layer or region or medium or film))) and	EPO; JPO;	
		372/46) and saturable near absorption	DERWENT; IBM TDB	
101		(least peet diade) and cloded and active and contact	_	2003/04/03 16:41
164	1	(laser near diode) and clad\$4 and active and contact	USPAT; US-PGPUB;	2003/04/03 10.41
		and electrode and (ridge or stripe) and (etching near		
		stop near (layer or region or medium or film)) and saturable near absorption and 372/46	EPO; JPO; DERWENT;	
		saturable hear absorption and 372/46	IBM TDB	
	33	(laser near diode) and clad\$4 and active and contact	USPAT;	2003/04/02 14:55
-	33	and electrode and (injection near3 stripe) and voltage	US-PGPUB;	2003/04/02 14:33
		and electrode and (injection riears stripe) and voltage	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
	26	((laser near diode) and clad\$4 and active and contact	USPAT;	2003/04/02 14:55
-	20	and electrode and (injection near3 stripe) and	US-PGPUB;	2000/04/02 : 11.00
	!	voltage) and 372/\$	EPO; JPO;	
		Voltage, and 072,4	DERWENT;	
			IBM TDB	
_	53	laser and clad\$4 and active and contact and	USPAT;	2003/04/03 09:01
		electrode and (injection near3 stripe) and voltage	US-PGPUB:	
		Coordinate and the transfer of the contract of	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	10	laser and clad\$4 and active and contact and	USPAT;	2003/04/03 06:12
		electrode and (injection near stripe) and voltage	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	29	laser and clad\$4 and active and contact and	USPAT;	2003/04/03 08:47
		electrode and (injection near2 stripe) and voltage	US-PGPUB;	
			EPO; JPO;	
		• •	DERWENT;	
	_		IBM_TDB	
-	2	laser and clad\$4 and active and contact and	USPAT;	2003/04/03 16:07
		electrode and (injection near2 stripe) and voltage and	US-PGPUB;	
		(etching near stop near (layer or region or medium or	EPO; JPO;	
		film))	DERWENT;	
	2	land and staded and active and contact and	IBM_TDB USPAT;	2003/04/03 16:06
-	2	laser and clad\$4 and active and contact and electrode and (injection near2 stripe) and voltage and	US-PGPUB;	2003/04/03 10.00
		(etch\$4 near stop)	EPO; JPO;	
		(etchiva hear stop)	DERWENT;	
			IBM TDB	
-	12	laser and clad\$4 and active and contact and	USPAT;	2003/04/03 08:57
	,_	electrode and (injection near2 stripe) and voltage and	US-PGPUB;	
		(etch\$4 near (layer or region or medium or film))	EPO; JPO;	
		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	DERWENT;	
			IBM TDB	
-	1	(laser and clad\$4 and active and contact and	USPAT;	2003/04/03 08:57
		electrode and (injection near2 stripe) and voltage and	US-PGPUB;	
		(etch\$4 near (layer or region or medium or film)))	EPO; JPO;	
		and third near clad	DERWENT;	
			IBM_TDB	
•	1	(laser and clad\$4 and active and contact and	USPAT;	2003/04/03 09:09
		electrode and (injection near2 stripe) and voltage and	US-PGPUB;	
		(etch\$4 near (layer or region or medium or film)))	EPO; JPO;	
		and third near clad\$4	DERWENT;	
			IBM_TDB	

-	364	((laser or diode) with (ridge or stripe)) and clad\$4	USPAT;	2003/04/03 09:06
		and active and contact and electrode and voltage	US-PGPUB;	
		and 372/46	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	137	((laser NEAR diode) with (ridge or stripe)) and	USPAT;	2003/04/03 09:07
	!	clad\$4 and active and contact and electrode and	US-PGPUB;	
		voltage	EPO; JPO;	
		•	DERWENT;	
			IBM_TDB	
-	12	(((laser NEAR diode) with (ridge or stripe)) and	USPAT;	2003/04/03 09:21
	1	clad\$4 and active and contact and electrode and	US-PGPUB;	
		voltage) and third near clad\$4	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	5	((((laser NEAR diode) with (ridge or stripe)) and	USPAT;	2003/04/03 13:02
		clad\$4 and active and contact and electrode and	US-PGPUB;	
		voltage) and third near clad\$4) and 372/46	EPO; JPO;	
			DERWENT;	
			IBM_TDB	